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**CERTIFICATE OF TRANSMISSION****December 20, 2002**

<b>Atty Docket No.:</b>	TKHR4540
<b>Appl. No.:</b>	09/467,675
<b>Filing Date:</b>	December, 21, 1999
<b>Pages:</b>	Cover + 10

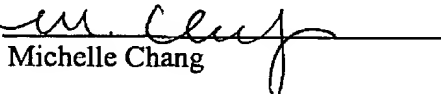
**BY FACSIMILE ONLY**

**Fax No.:** 703-872-9319  
**Attention:** Examiner NADAV, ORI  
**Group Unit:** 2811  
**From:** Jiawei Huang, Reg. No. 43,330  
**MESSAGE:** Enclosed is an Amendment in 10 pages.

**FAX RECEIVED****DEC 20 2002****TECHNOLOGY CENTER 2800**

Sir:

I hereby certify that this correspondence is being facsimile transmitted to the Patent and Trademark Office on **December 20, 2002** at the above indicated fax number.

Sign by:   
Michelle Chang

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Atty D cket No.: TKHR4540

Serial No.: 09/467,675

#17/C  
(N.E.)  
1-13-03  
L. Spruell**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of :  
Application No. : 09/467,675  
Filed : December 21, 1999  
For : Structure For ESD Protection With Single Crystal Silicon Sided Junction  
Applicant : Liou et al.  
Examiner : Ori Nadav  
Art Unit : 2811

**FAX RECEIVED****AMENDMENT AND RESPONSE TO OFFICE ACTION**

DEC 20 2002

Assistant Commissioner of Patents and Trademarks  
Washington, DC 20231

**TECHNOLOGY CENTER 2800**

Sir:

In response to the Office Action dated September 30, 2002, please consider the following remarks.

**In The Claims:**

Please substitute the following clean text claims for the pending claims having the same number.

1. (Thrice Amended) An ESD protection structure having a single crystal Si-sided diode used to protect an internal circuit, the ESD protection structure electrically connected between an input pad and a node and the internal circuit electrically connected to the node, the ESD protection structure comprising: